



STGD10NC60S STGP10NC60S

10 A, 600 V fast IGBT

Features

- Optimized performance for medium operating frequencies up to 5 kHz in hard switching
- Low on-voltage drop ($V_{CE(sat)}$)

Application

- Motor drive

Description

This IGBT utilizes the advanced PowerMESH™ process resulting in an excellent trade-off between switching performance and low on-state behavior.

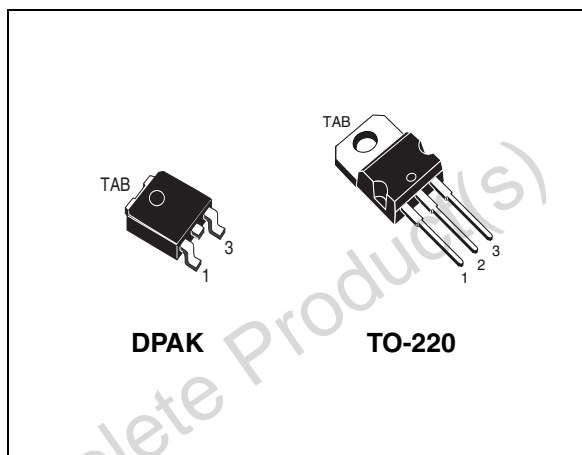


Figure 1. Internal schematic diagram

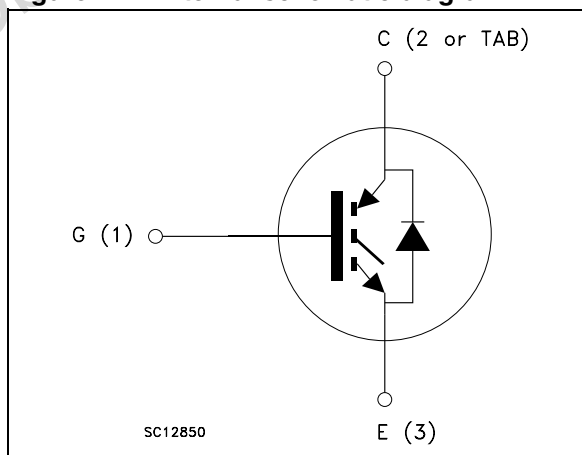


Table 1. Device summary

| Order codes | Marking | Package | Packaging |
|---------------|-----------|---------|---------------|
| STGD10NC60ST4 | GD10NC60S | DPAK | Tape and reel |
| STGP10NC60S | GP10NC60S | TO-220 | Tube |

Contents

| | | |
|----------|---|-----------|
| 1 | Electrical ratings | 3 |
| 2 | Electrical characteristics | 4 |
| 2.1 | Electrical characteristics (curves) | 5 |
| 3 | Test circuits | 8 |
| 4 | Package mechanical data | 9 |
| 5 | Packaging mechanical data | 14 |
| 6 | Revision history | 17 |

Obsolete Product(s) - Obsolete Product(s)



1 Electrical ratings

Table 2. Absolute maximum ratings

| Symbol | Parameter | Value | | Unit |
|--------------------------------|---|------------|--------|------|
| | | DPAK | TO-220 | |
| V _{CES} | Collector-emitter voltage (V _{GE} = 0) | 600 | | V |
| I _C ⁽¹⁾ | Continuous collector current at T _C = 25 °C | 18 | 21 | A |
| I _C ⁽¹⁾ | Continuous collector current at T _C = 100 °C | 10 | 11 | A |
| I _{CL} ⁽²⁾ | Turn-off latching current | 14 | | A |
| I _{CP} ⁽³⁾ | Pulsed collector current | 25 | | A |
| V _{GE} | Gate-emitter voltage | ±20 | | V |
| P _{TOT} | Total dissipation at T _C = 25 °C | 60 | 62.5 | W |
| T _j | Operating junction temperature | -55 to 150 | | °C |

1. Calculated according to the iterative formula:

$$I_C(T_C) = \frac{T_{j(max)} - T_C}{R_{thj-c} \times V_{CE(sat)(max)}(T_{j(max)}, I_C(T_C))}$$

2. V_{clamp} = 80%.(V_{CES}), T_j = 150 °C, R_G = 10 Ω, V_{GE} = 15 V
 3. Pulse width limited by maximum junction temperature and turn-off within RBSOA

Table 3. Thermal data

| Symbol | Parameter | Value | | Unit |
|-------------------|-------------------------------------|-------|--------|------|
| | | DPAK | TO-220 | |
| R _{thJC} | Thermal resistance junction-case | 2.08 | 2 | °C/W |
| R _{thJA} | Thermal resistance junction-ambient | 100 | 62.5 | °C/W |

2 Electrical characteristics

$T_J = 25\text{ °C}$ unless otherwise specified.

Table 4. Static

| Symbol | Parameter | Test conditions | Min. | Typ. | Max. | Unit |
|---------------|--|--|------|--------------|-----------|---------------------|
| $V_{(BR)CES}$ | Collector-emitter breakdown voltage ($V_{GE} = 0$) | $I_C = 1\text{ mA}$ | 600 | | | V |
| $V_{CE(sat)}$ | Collector-emitter saturation voltage | $V_{GE} = 15\text{ V}$, $I_C = 5\text{ A}$ $V_{GE} = 15\text{ V}$, $I_C = 5\text{ A}$, $T_J = 125\text{ °C}$ | | 1.45 1.45 | 1.65 | V V |
| $V_{GE(th)}$ | Gate threshold voltage | $V_{CE} = V_{GE}$, $I_C = 250\text{ }\mu\text{A}$ | 3.75 | | 5.75 | V |
| I_{CES} | Collector cut-off current ($V_{GE} = 0$) | $V_{CE} = 600\text{ V}$ $V_{CE} = 600\text{ V}$, $T_J = 125\text{ °C}$ | | | 150 1 | μA mA |
| I_{GES} | Gate-emitter leakage ($V_{CE} = 0$) | $V_{GE} = \pm 20\text{ V}$ | | | ± 100 | nA |
| g_{fs} | Forward transconductance | $V_{CE} = 15\text{ V}$, $I_C = 5\text{ A}$ | | 3.5 | | S |

Table 5. Dynamic

| Symbol | Parameter | Test conditions | Min. | Typ. | Max. | Unit |
|-----------|------------------------------|--|------|------|------|------|
| C_{ies} | Input capacitance | $V_{CE} = 25\text{ V}$, $f = 1\text{ MHz}$, $V_{GE} = 0$ | | 365 | | pF |
| C_{oes} | Output capacitance | | - | 44 | - | pF |
| C_{res} | Reverse transfer capacitance | | | 8 | | pF |
| Q_g | Total gate charge | $V_{CE} = 480\text{ V}$, $I_C = 5\text{ A}$, | | 18 | | nC |
| Q_{ge} | Gate-emitter charge | $V_{GE} = 15\text{ V}$ | - | 8 | - | nC |
| Q_{gc} | Gate-collector charge | Figure 16 | | 3.5 | | nC |

Table 6. Switching on/off (inductive load)

| Symbol | Parameter | Test conditions | Min. | Typ. | Max. | Unit |
|----------------|-----------------------|---|------|------|------|------------------|
| $t_{d(on)}$ | Turn-on delay time | $V_{CC} = 390\text{ V}$, $I_C = 5\text{ A}$ $R_G = 10\text{ }\Omega$, $V_{GE} = 15\text{ V}$, Figure 17 | | 19 | | ns |
| t_r | Current rise time | | - | 4 | - | ns |
| $(di/dt)_{on}$ | Turn-on current slope | | | 1330 | | A/ μs |
| $t_{d(on)}$ | Turn-on delay time | $V_{CC} = 390\text{ V}$, $I_C = 5\text{ A}$ $R_G = 10\text{ }\Omega$, $V_{GE} = 15\text{ V}$, $T_J = 125\text{ °C}$ Figure 17 | | 18 | | ns |
| t_r | Current rise time | | - | 4.5 | - | ns |
| $(di/dt)_{on}$ | Turn-on current slope | | | 1000 | | A/ μs |
| $t_r(V_{off})$ | Off voltage rise time | $V_{CC} = 390\text{ V}$, $I_C = 5\text{ A}$, $R_G = 10\text{ }\Omega$, $V_{GE} = 15\text{ V}$, Figure 17 | | 100 | | ns |
| $t_{d(off)}$ | Turn-off delay time | | - | 160 | - | ns |
| t_f | Current fall time | | | 205 | | ns |
| $t_r(V_{off})$ | Off voltage rise time | $V_{CC} = 390\text{ V}$, $I_C = 5\text{ A}$, $R_G = 10\text{ }\Omega$, $V_{GE} = 15\text{ V}$, $T_J = 125\text{ °C}$ Figure 17 | | 165 | | ns |
| $t_{d(off)}$ | Turn-off delay time | | - | 250 | - | ns |
| t_f | Current fall time | | | 310 | | ns |

Table 7. Switching energy (inductive load)

| Symbol | Parameter | Test conditions | Min | Typ. | Max | Unit |
|-----------------|---------------------------|--|-----|------|-----|---------------|
| $E_{on}^{(1)}$ | Turn-on switching losses | $V_{CC} = 480\text{ V}, I_C = 5\text{ A}$ | | 60 | | μJ |
| $E_{off}^{(2)}$ | Turn-off switching losses | $R_G = 10\ \Omega, V_{GE} = 15\text{ V},$ <i>Figure 15</i> | - | 340 | - | μJ |
| E_{ts} | Total switching losses | | | 400 | | μJ |
| $E_{on}^{(1)}$ | Turn-on switching losses | $V_{CC} = 480\text{ V}, I_C = 5\text{ A}$ | | 90 | | μJ |
| $E_{off}^{(2)}$ | Turn-off switching losses | $R_G = 10\ \Omega, V_{GE} = 15\text{ V},$ $T_J = 125^\circ\text{C}$ <i>Figure 15</i> | - | 540 | - | μJ |
| E_{ts} | Total switching losses | | | 630 | | μJ |

1. E_{on} is the turn-on losses when a typical diode is used in the test circuit in *Figure 15*. If the IGBT is offered in a package with a co-pack diode, the co-pack diode is used as external diode. IGBT's and diode are at the same temperature
2. Turn-off losses included also include also the tail of the collector current

2.1 Electrical characteristics (curves)

Figure 2. Output characteristics

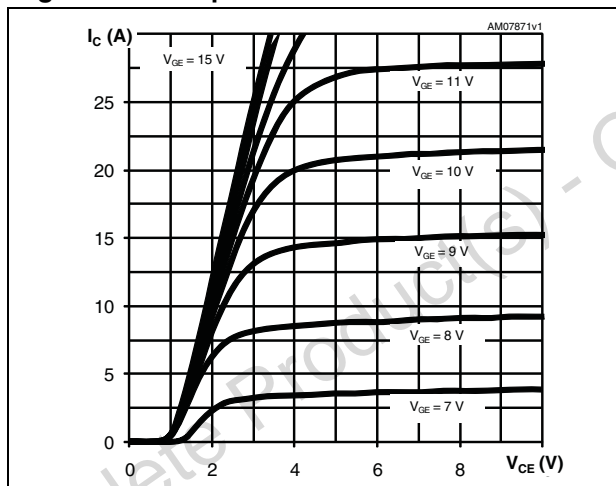


Figure 3. Transfer characteristics

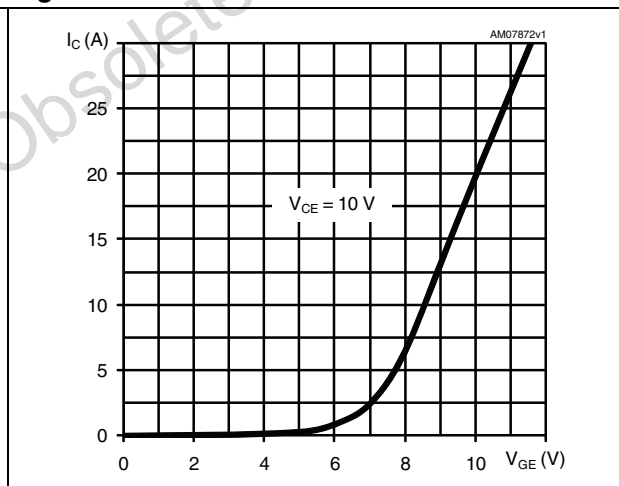


Figure 4. Collector-emitter on voltage vs. collector current

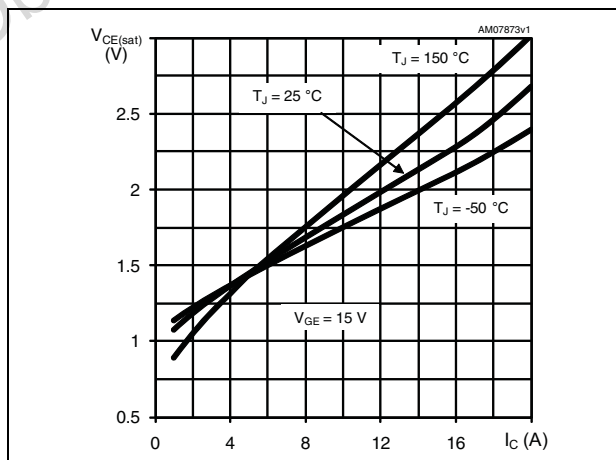


Figure 5. Collector-emitter on voltage vs. temperature

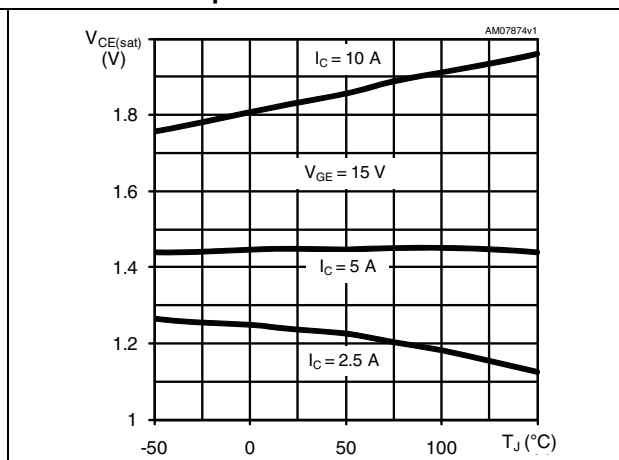


Figure 6. Normalized breakdown voltage vs. temperature

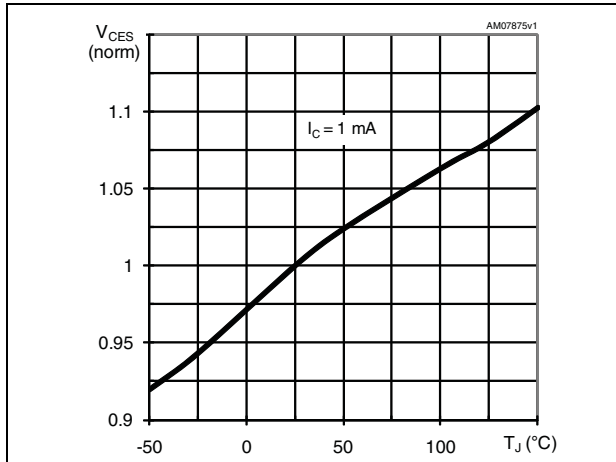


Figure 7. Normalized gate threshold voltage vs. temperature

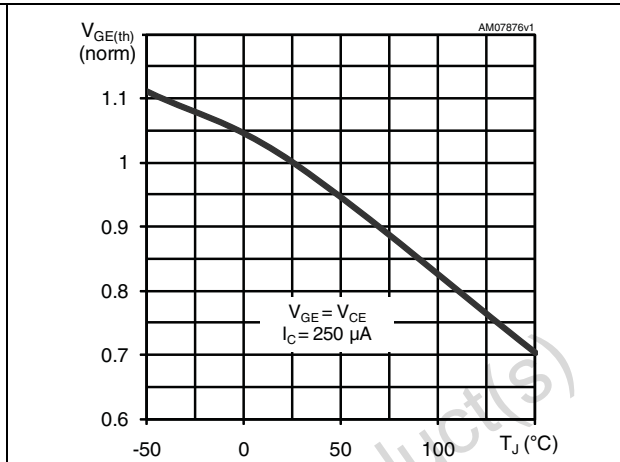


Figure 8. Gate charge vs. gate-emitter voltage

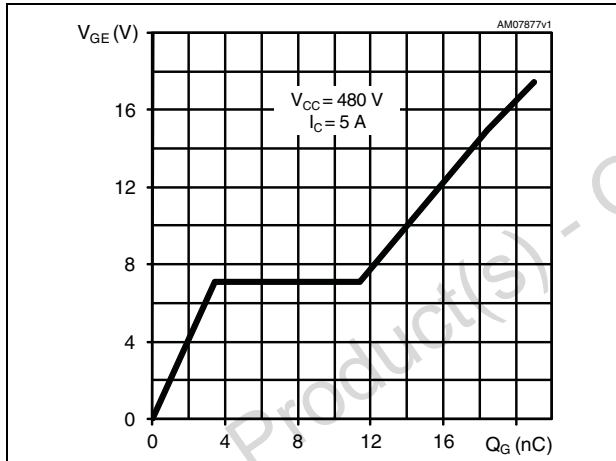


Figure 9. Capacitance variations

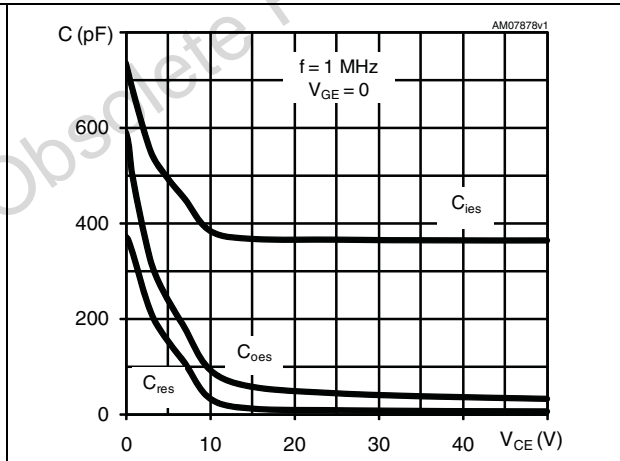


Figure 10. Switching losses vs. temperature

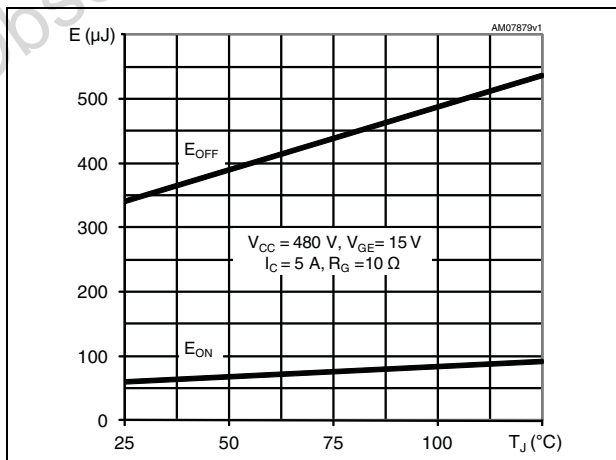


Figure 11. Switching losses vs. gate resistance

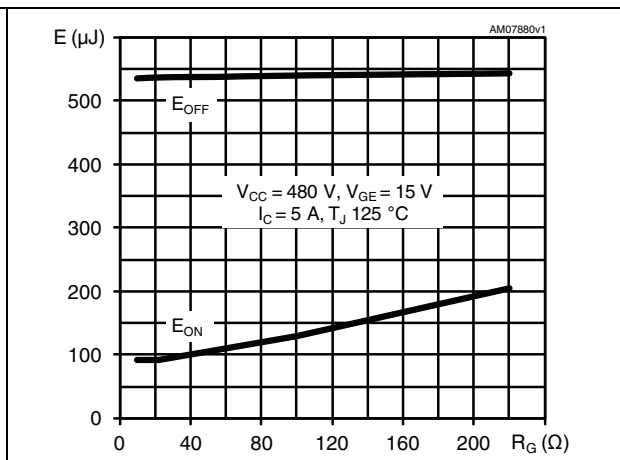


Figure 12. Switching losses vs. collector current

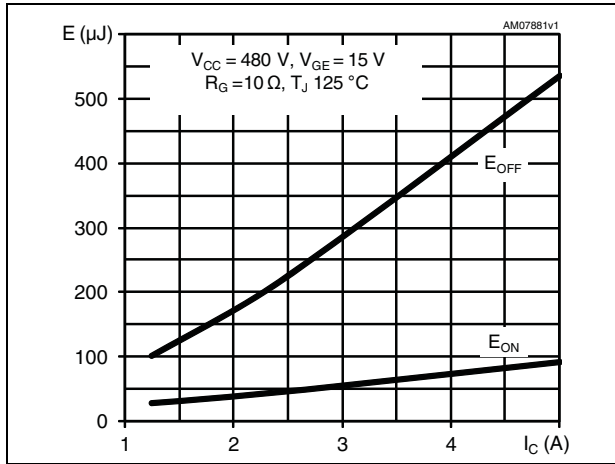


Figure 13. Turn-off SOA

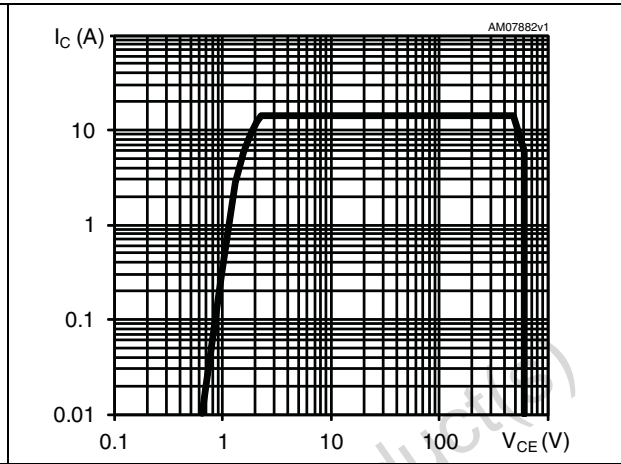
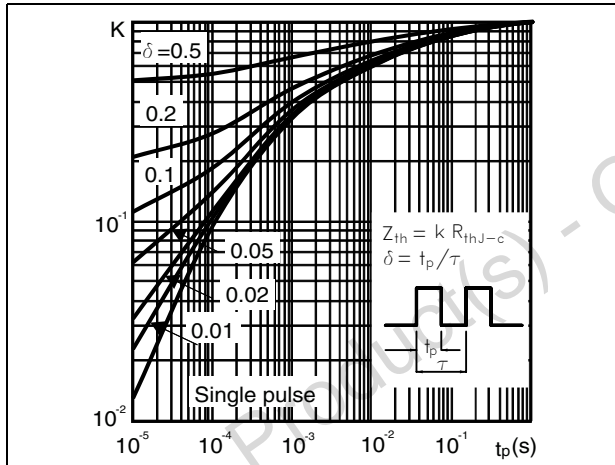


Figure 14. Thermal impedance for DPAK and TO-220



3 Test circuits

Figure 15. Test circuit for inductive load switching

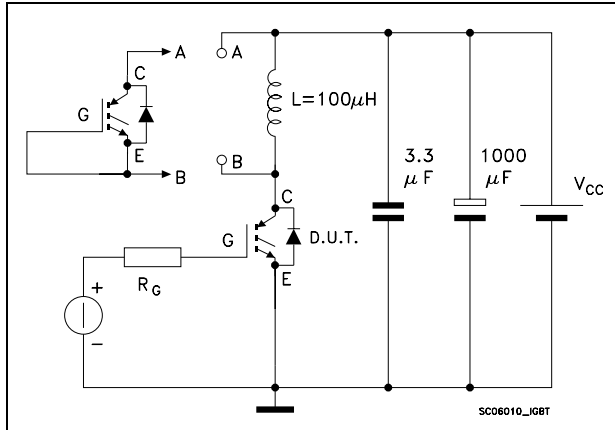


Figure 16. Gate charge test circuit

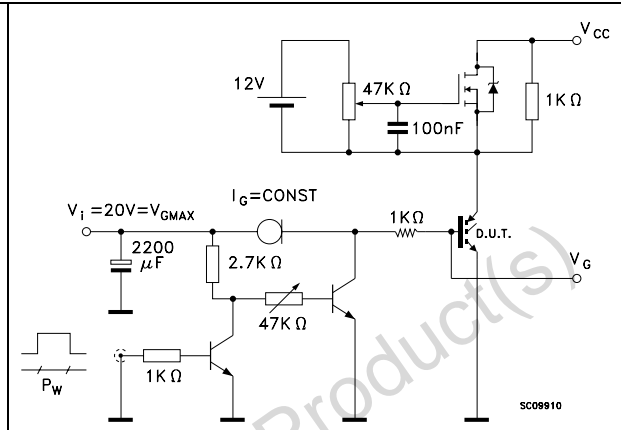
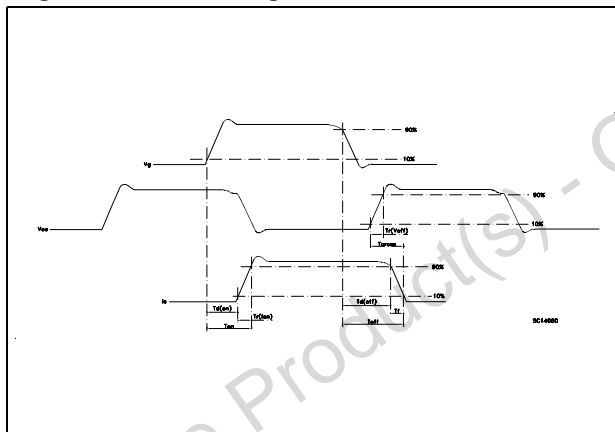


Figure 17. Switching waveforms



4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

Obsolete Product(s) - Obsolete Product(s)

Table 8. DPAK (TO-252) mechanical data

| Dim. | mm | | |
|------|------|------|-------|
| | Min. | Typ. | Max. |
| A | 2.20 | | 2.40 |
| A1 | 0.90 | | 1.10 |
| A2 | 0.03 | | 0.23 |
| b | 0.64 | | 0.90 |
| b4 | 5.20 | | 5.40 |
| c | 0.45 | | 0.60 |
| c2 | 0.48 | | 0.60 |
| D | 6.00 | | 6.20 |
| D1 | | 5.10 | |
| E | 6.40 | | 6.60 |
| E1 | | 4.70 | |
| e | | 2.28 | |
| e1 | 4.40 | | 4.60 |
| H | 9.35 | | 10.10 |
| L | 1 | | |
| L1 | | 2.80 | |
| L2 | | 0.80 | |
| L4 | 0.60 | | 1 |
| R | | 0.20 | |
| V2 | 0° | | 8° |

Figure 18. DPAK (TO-252) drawing

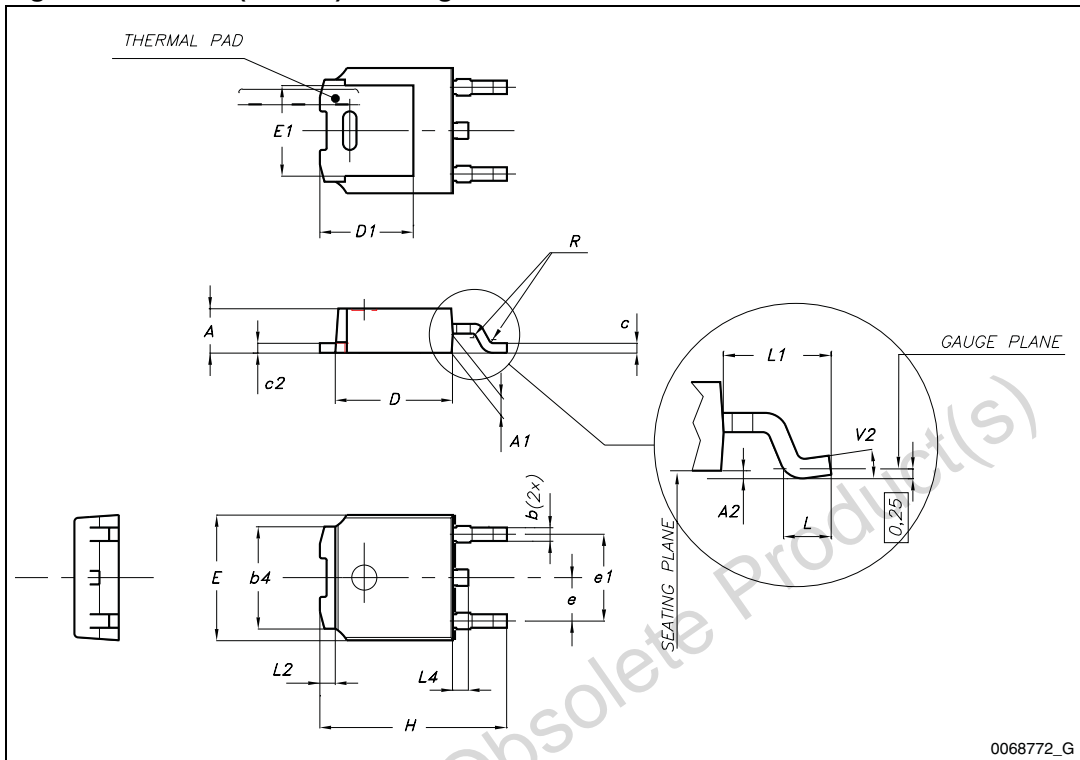
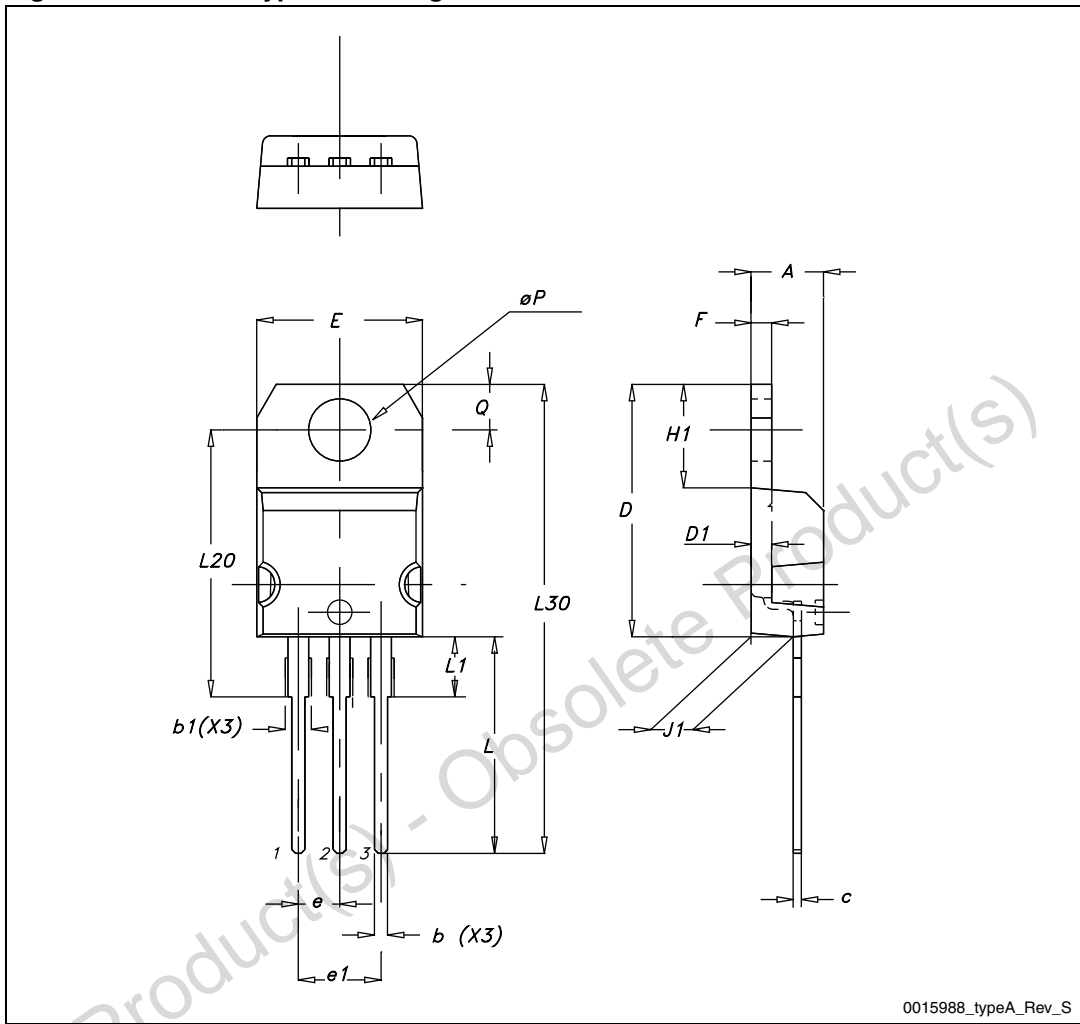


Table 9. TO-220 type A mechanical data

| Dim. | mm | | |
|------|-------|-------|-------|
| | Min. | Typ. | Max. |
| A | 4.40 | | 4.60 |
| b | 0.61 | | 0.88 |
| b1 | 1.14 | | 1.70 |
| c | 0.48 | | 0.70 |
| D | 15.25 | | 15.75 |
| D1 | | 1.27 | |
| E | 10 | | 10.40 |
| e | 2.40 | | 2.70 |
| e1 | 4.95 | | 5.15 |
| F | 1.23 | | 1.32 |
| H1 | 6.20 | | 6.60 |
| J1 | 2.40 | | 2.72 |
| L | 13 | | 14 |
| L1 | 3.50 | | 3.93 |
| L20 | | 16.40 | |
| L30 | | 28.90 | |
| ØP | 3.75 | | 3.85 |
| Q | 2.65 | | 2.95 |

Figure 19. TO-220 type A drawing



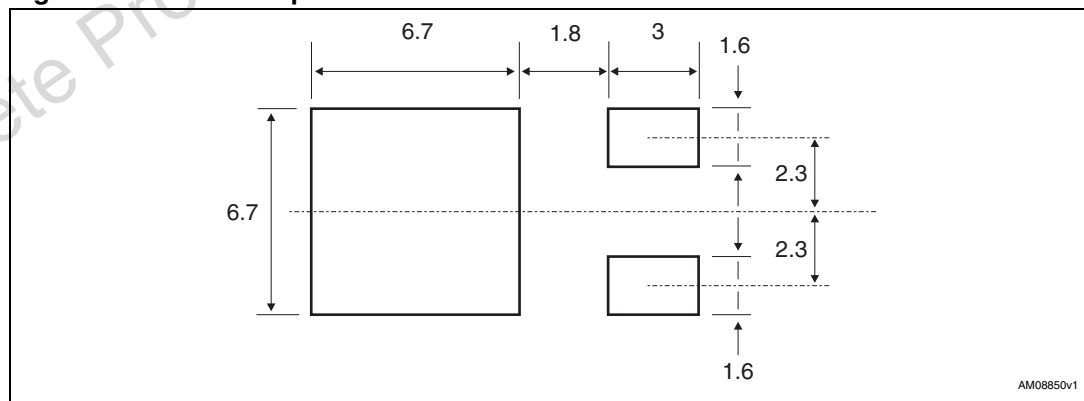
0015988_typeA_Rev_S

5 Packaging mechanical data

Table 10. DPAK (TO-252) tape and reel mechanical data

| Tape | | | Reel | | |
|------|------|------|------|-----------|------|
| Dim. | mm | | Dim. | mm | |
| | Min. | Max. | | Min. | Max. |
| A0 | 6.8 | 7 | A | | 330 |
| B0 | 10.4 | 10.6 | B | 1.5 | |
| B1 | | 12.1 | C | 12.8 | 13.2 |
| D | 1.5 | 1.6 | D | 20.2 | |
| D1 | 1.5 | | G | 16.4 | 18.4 |
| E | 1.65 | 1.85 | N | 50 | |
| F | 7.4 | 7.6 | T | | 22.4 |
| K0 | 2.55 | 2.75 | | | |
| P0 | 3.9 | 4.1 | | Base qty. | 2500 |
| P1 | 7.9 | 8.1 | | Bulk qty. | 2500 |
| P2 | 1.9 | 2.1 | | | |
| R | 40 | | | | |
| T | 0.25 | 0.35 | | | |
| W | 15.7 | 16.3 | | | |

Figure 20. DPAK footprint^(a)



a. All dimension are in millimeters

Figure 21. Tape for DPAK (TO-252)

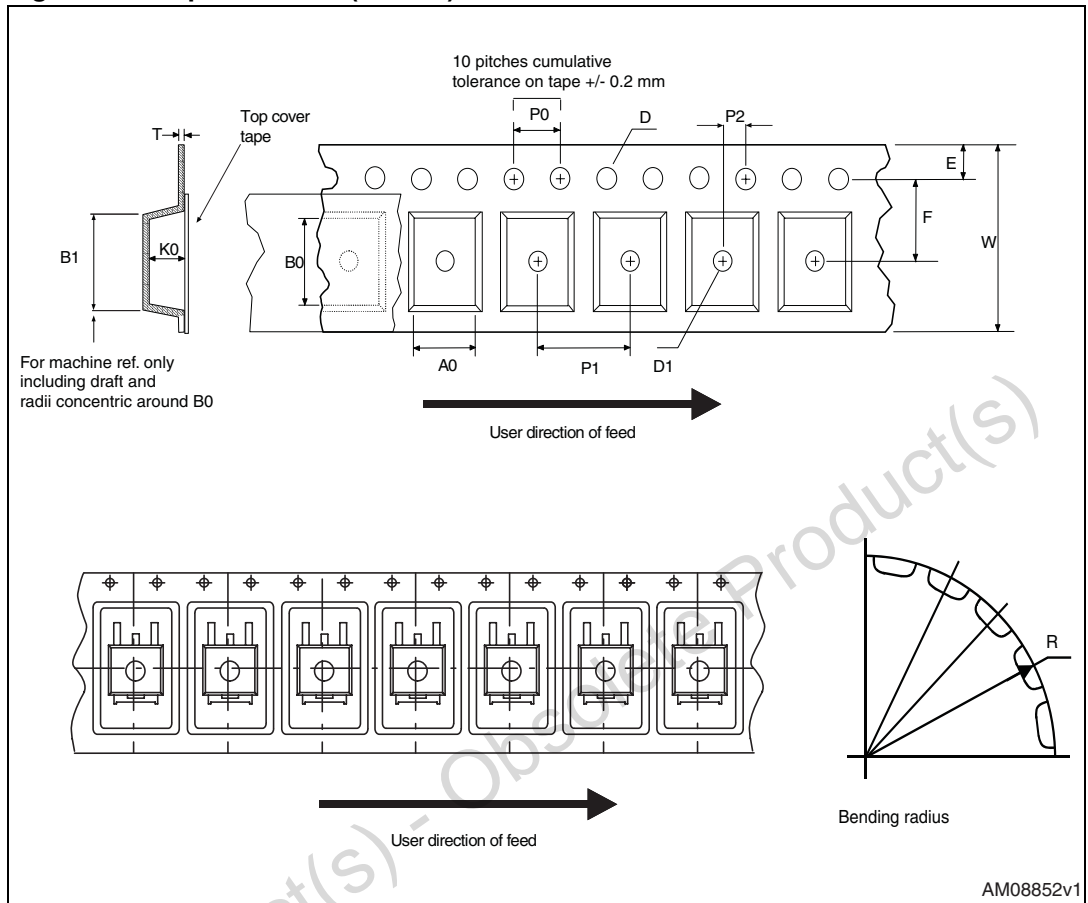
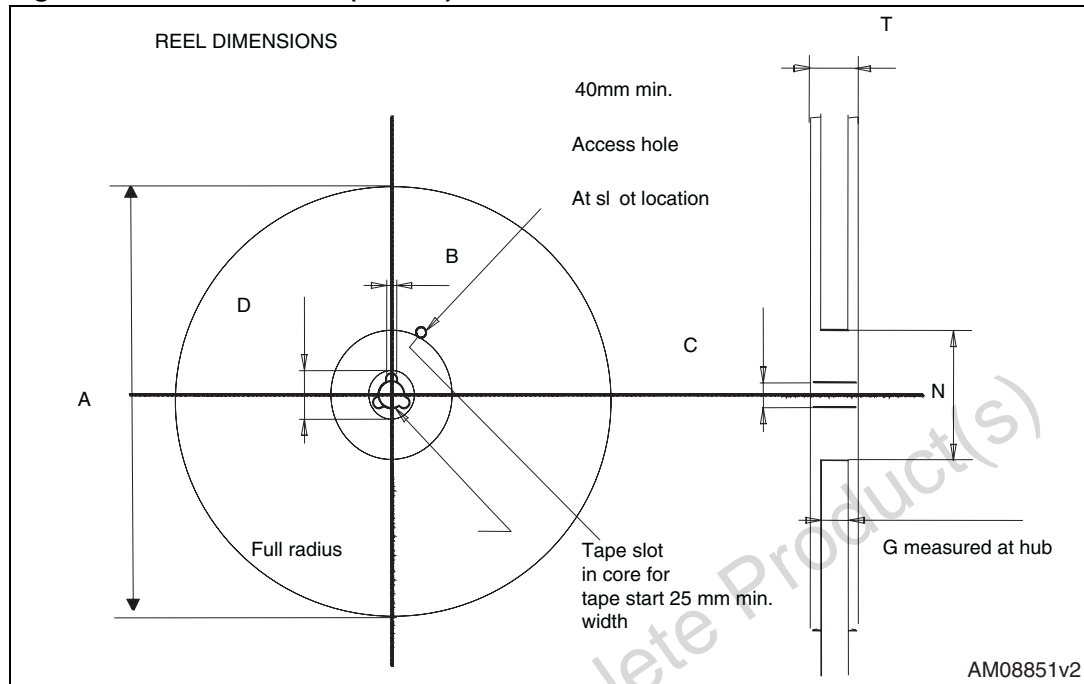


Figure 22. Reel for DPAK (TO-252)



AM08851v2

6 Revision history

Table 11. Document revision history

| Date | Revision | Changes |
|-------------|----------|--|
| 06-Jul-2009 | 1 | Initial release |
| 17-Dec-2010 | 2 | Inserted <i>Section 2.1: Electrical characteristics (curves) on page 5</i> |

Obsolete Product(s) - Obsolete Product(s)

Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZED ST REPRESENTATIVE, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2010 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Philippines - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com